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FROM
Intellectual Property Group of
Pillsbury Winthrop LLP
Attorneys at Law
P.O. Box 10500
McLean, VA 22102

Telephone: (703) 905-2000

Our Facsimile #: (703) 905-2500

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| TO THE PATENT | APPLICATION of | | | |
| Inventor(3) | | Group Art U | nit: 2826 | |
| Appln. No | | Examiner: | Mondt, Jonanne | s P. |
| <u>series co</u> Fil ed : | de † † <u>serial no.</u> September 15, 2000 | 1 Ph. | Dia 0074400 | |
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Attorney's Docket 020847-0271420 Client Reference: TFN990143-US

From-PILLSBURY WINTHROP

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION of:

HAMADA

For:

Application No.: 09/663,340

Filed: September 15, 2000

Group Art Unit: 2826

Examiner: Mondt, Johannes P.

Confirmation Number: 1868

POWER SEMICONDUCTOR DEVICE AND PRODUCTION METHOD FOR

THE SAME

Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

AMENDMENT/RESPONSE TRANSMITTAL

Transmitted herewith is an amendment/response for this application.

The fee for claims and extension of time (37 C.F.R. 1.16 and 1.17) has been calculated as shown below:

| | CLAIMS REMAINING AFTER AMENDMENT | HIGHE: PREVIO PAID | DUSLY | PR | ESENT XTRA | | R.A | TE | | ADDIT. FEE | |
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HAMADA ~ 09/663,340 Client/Matter: 020847-0271420

FEE PAYMENT

Authorization is hereby made to charge the amount of \$0.00 to Deposit Account No. 033975. Charge any additional fees required by this paper or credit any overpayment in the manner authorized above. A duplicate of this paper is attached.

Date: March 12, 2004
PILLSBURY WINTHROP LLP
P.O. Box 10500
McLean, VA 22102

(703) 905-2045

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From-PILLSBURY WINTHROP

Attorney's Docket 020847-0271420 Client Reference: TFN990143-US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION of:

Confirmation Number: 1868

HAMADA

Mar-12-2004 14:04

Application No.: 09/663,340

Group Art Unit: 2826

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Filed: September 15, 2000

Examiner: Mondt, Johannes P.

For:

POWER SEMICONDUCTOR DEVICE AND PRODUCTION METHOD FOR

THE SAME

Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

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The fee for claims and extension of time (37 C.F.R. 1.16 and 1.17) has been calculated as shown below:

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Date: March 12, 2004 PILLSBURY WINTHROP LLP P.O. Box 10500 McLean, VA 22102 (703) 905-2045

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MAR 1 2 2004

Attorney Docket: 020847-0271420 Client Reference: TFN990143-US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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Application No.: 09/663,340 Filed: September 15, 2000

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Title: POWER SEMICONDUCTOR DEVICE AND PRODUCTION METHOD FOR THE

SAME

AMENDMENT

Mail Stop Non-Fee Amendments Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In reply to the Office Action dated January 16, 2004, please amend the aboveidentified application as follows:

IN THE CLAIMS:

This listing of claims will replace all prior versions, and listings, of claims in the application:

- 1. (Previously presented) A semiconductor device comprising:
- a body region of a first conductivity type formed in a semiconductor substrate and having a major surface opposite to a surface shared between the semiconductor substrate and the body region;
 - a plurality of trench gates extending through the body region;
- a plurality of first semiconductor regions of a second conductivity type that is different from the first conductivity type, the first semiconductor regions having a first depth as measured from said major surface of the body region, at least a portion of the first semiconductor regions flanking the trench gates on both of their sides and being in contact with said trench gates via films bordering and insulating the trench gates;

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